

STTH10002

Ultrafast recovery diode

Main product characteristics

I _{F(AV)}	2 x 50 A
V _{RRM}	200 V
T _j (max)	150° C
V _F (typ)	0.72 V
t _{rr} (typ)	30 ns

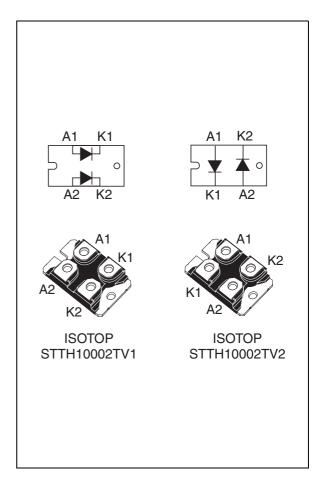
Features and benefits

- Very low forward losses
- Low recovery time
- High surge current capability
- Insulated
 - Insulating voltage = 2500 V_{rms}
 - Capacitance = 45 pF

Description

The STTH10002 is a dual rectifier suited for welding equipment, and high power industrial applications.

Packaged in ISOTOP, this device is intended for use in the secondary rectification of power converters.



Order codes

Part Number	Marking
STTH10002TV1	STTH10002TV1
STTH10002TV2	STTH10002TV2

Characteristics STTH10002

Characteristics 1

Absolute ratings (limiting values at $T_i = 25^{\circ}$ C, unless otherwise specified) Table 1.

Symbol	Para	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	Repetitive peak reverse voltage		V
I _{F(RMS)}	RMS forward current Per diode		150	Α
Average forward overent S. O.E.	Per diode T _c = 100° C	- 50	Α	
¹F(AV)	$I_{F(AV)}$ Average forward current, $\delta = 0.5$	Per device T _c = 95° C	50	"
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$		750	Α
T _{stg}	Storage temperature range		-55 to + 175	°C
T _j	Maximum operating junction temperature			°C

Table 2. **Thermal parameters**

Symbol	Parameter		Value	Unit
В	D. Limstian to acco	Per diode	1	
R _{th(j-c)} Junction to case	Total	0.55	° C/W	
R _{th(c)}	Coupling		0.1	

When the two diodes 1 and 2 are used simultaneously:

 $\Delta Tj(diode\ 1) = P\ (diode\ 1)\ X\ R_{th(j-c)}\ (Per\ diode) + P\ (diode\ 2)\ x\ R_{th(c)}$

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
ı (1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25° C	V _R = V _{RRM}			50	μА
'R`		T _j = 125° C			50	500	
	V _F ⁽²⁾ Forward voltage drop	T _j = 25° C	I _F = 50 A			1	
			I _F = 100 A			1.15	
V _F ⁽²⁾		T _j = 125° C	I _F = 100 A		0.90	1.0	V
	T _j = 150° C	T 150° C	I _F = 50 A		0.72	0.80	
		1 _j = 150° C	I _F = 100 A		0.86	0.97	

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation: P = 0.63 x $I_{F(AV)}$ + 0.0034 $I_{F}^{2}_{(RMS)}$

$$P = 0.63 \times I_{F(AV)} + 0.0034 I_{F^{2}(RMS)}$$

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^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

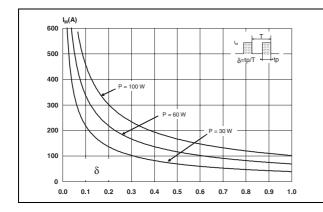
STTH10002 Characteristics

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур	Max.	Unit
t Dovorso recovery time		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		53	65	ns
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -200 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		30	37	
I _{RM}	Reverse recovery current	$I_F = 50 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, \ V_R = 160 \text{ V}, T_j = 125 ^{\circ}\text{C}$		10	13	Α
t _{fr}	Forward recovery time	$I_F = 50 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25 \text{ °C}$		180		ns
V _{FP}	Forward recovery voltage	$I_F = 50 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s},$ $T_j = 25 ^{\circ}\text{C}$		1.6		V

Figure 1. Peak current versus duty cycle

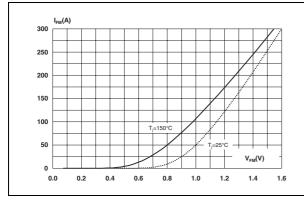
Figure 2. Forward voltage drop versus forward current (typical values, per diode)

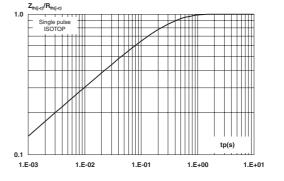


1_{FM}(A)
250
200
150
100
0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6

Figure 3. Forward voltage drop versus forward current (maximum values, per diode)

Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration

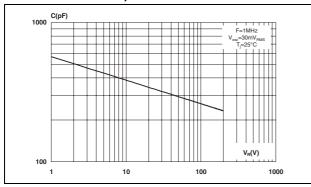




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Figure 5. Junction capacitance versus reverse applied voltage (typical values)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)



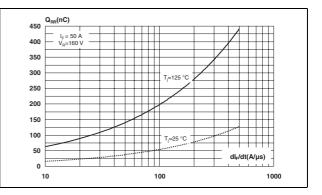
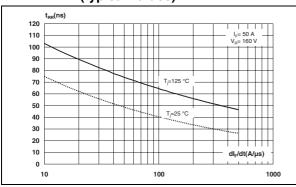


Figure 7. Reverse recovery time versus dI_F/dt Figure 8. Peak reverse recovery current (typical values)



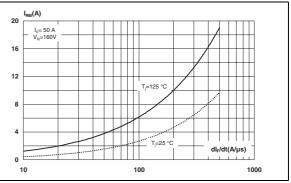
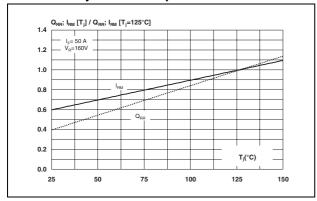
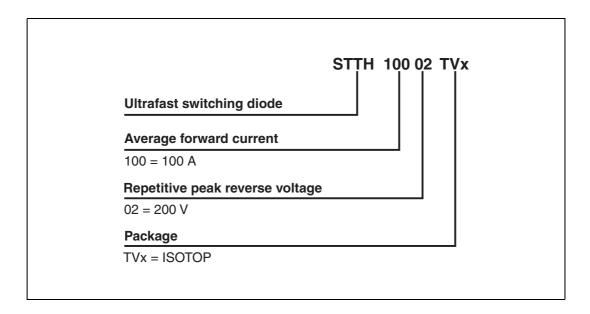


Figure 9. Dynamic parameters versus junction temperature



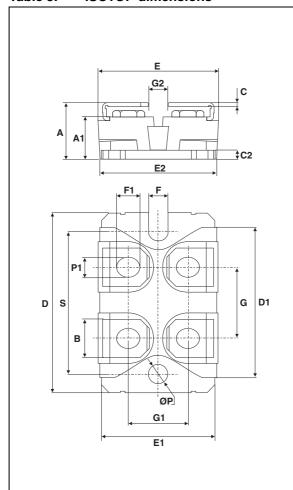
2 Ordering information scheme



Package information STTH10002

3 Package information

Table 5. ISOTOP dimensions



	DIMENSIONS				
REF.	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	11.80	12.20	0.465	0.480	
A1	8.90	9.10	0.350	0.358	
В	7.8	8.20	0.307	0.323	
С	0.75	0.85	0.030	0.033	
C2	1.95	2.05	0.077	0.081	
D	37.80	38.20	1.488	1.504	
D1	31.50	31.70	1.240	1.248	
Е	25.15	25.50	0.990	1.004	
E1	23.85	24.15	0.939	0.951	
E2	24.80 typ.		0.97	6 typ.	
G	14.90	15.10	0.587	0.594	
G1	12.60	12.80	0.496	0.504	
G2	3.50	4.30	0.138	0.169	
F	4.10	4.30	0.161	0.169	
F1	4.60	5.00	0.181	0.197	
Р	4.00	4.30	0.157	0.69	
P1	4.00	4.40	0.157	0.173	
S	30.10	30.30	1.185	1.193	

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH10002TV1	STTH10002TV1	ISOTOP	27 g	10	Tube
STTH10002TV2	STTH10002TV2	ISOTOP	27 g	10	Tube

5 Revision history

Date	Revision	Description of Changes
05-Apr-2006	1	First issue

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